

LOW POWER QUAD BIPOLAR OPERATIONAL AMPLIFIERS

- GOOD CONSUMPTION/SPEED RATIO :
ONLY 200 μ A FOR 2.1MHz, 2V/ μ s
- SINGLE (OR DUAL) SUPPLY OPERATION
FROM +4V TO +44V (\pm 2V TO \pm 22V)
- WIDE INPUT COMMON MODE MODE
VOLTAGE RANGE INCLUDING V_{CC}⁻
- LOW LEVEL OUTPUT VOLTAGE CLOSE TO
V_{CC}⁻ : 100mV TYPICAL
- PIN TO PIN COMPATIBLE WITH
STANDARD QUAD OP-AMPS

DESCRIPTION

The MC3x174 series are quad bipolar operational amplifier offering both low consumption (200 μ A) and good speed (2.1MHz, 2V/ μ s).

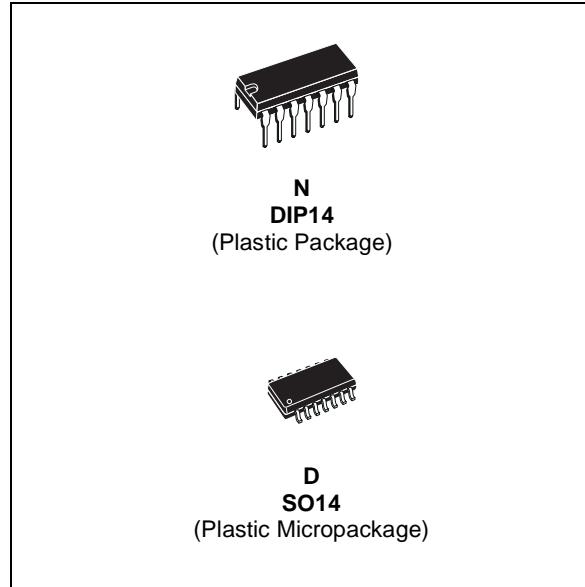
Moreover the Input Common Mode Range extends down to the lower supply rail, allowing single supply operation from +4V to +44V.

ORDER CODE

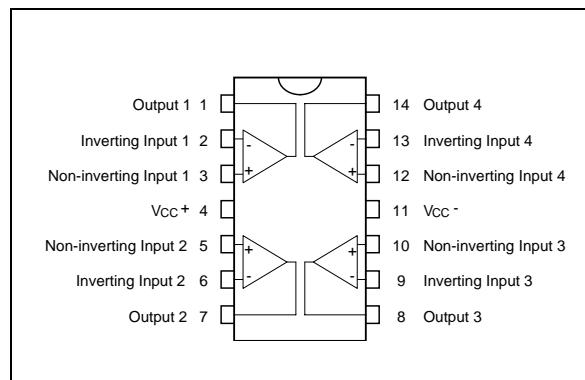
Part Number	Temperature Range	Package	
		N	D
MC33174	-40°C, +105°C	•	•
MC35174	-55°C, +125°C	•	•
Example : MC33174N			

N = Dual in Line Package (DIP)

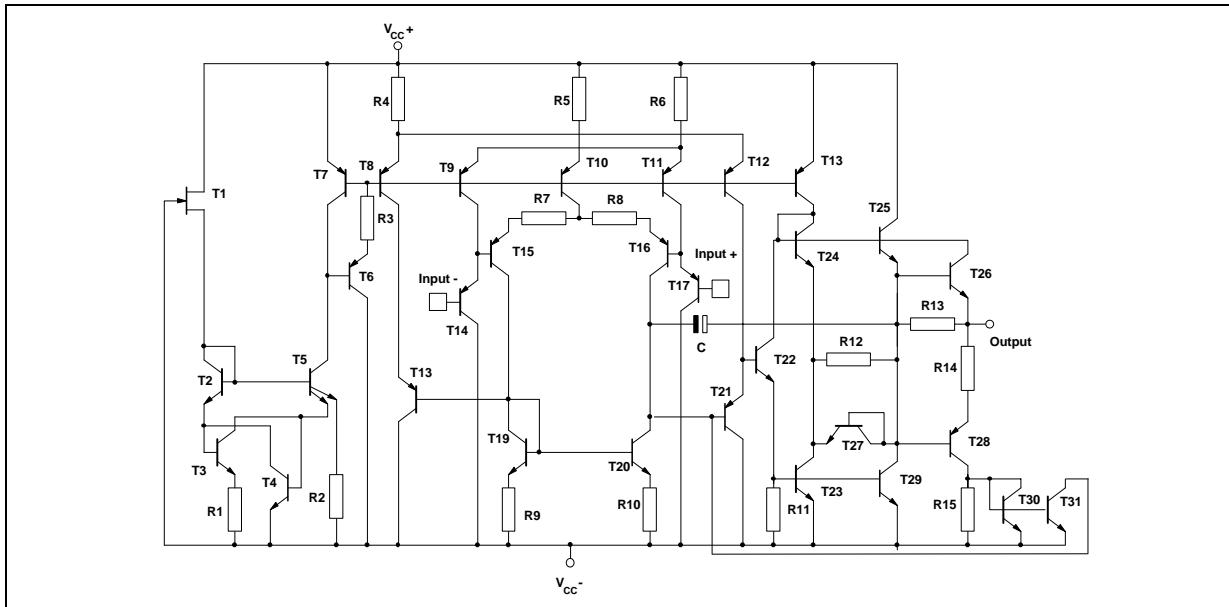
D = Small Outline Package (SO) - also available in Tape & Reel (DT)



PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM (for 1/4 MC33174)



MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	±22	V
V _{id}	Differential Input Voltage	see note 1)	V
V _i	Input Voltage	see note 1	V
	Output Short Circuit Duration	Indefinite	s
T _{oper}	Operating Free-Air Temperature range MC33174 MC35174	-40 to 105 -55 to 125	°C
T _j	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-65 to 150	°C

1. Either or both input voltages must not exceed the magnitude of V_{CC}.

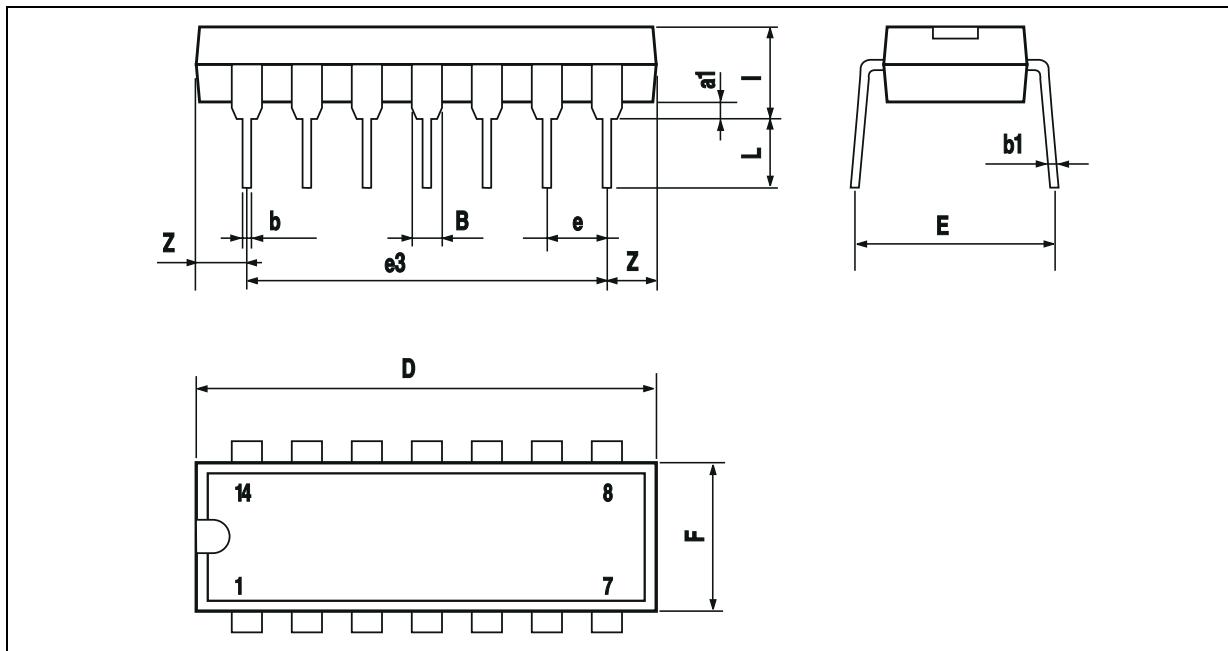
OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	±2 to ±22	V

ELECTRICAL CHARACTERISTICSV_{CC}⁺ = +15V, V_{CC}⁻ = -15V, R_L connected to Ground, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit	
V _{io}	Input Offset Voltage V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, V _{ic} = 0V V _{CC} ⁺ = 5V, V _{CC} ⁻ = 0V, V _{ic} = 0V, V _o = 1.4V V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, V _{ic} = 0V, T _{min.} ≤ T _{amb} ≤ T _{max.}		1 1	4.5 5 6.5	mV	
DV _{io}	Input Offset Voltage Drift		10		µV/°C	
I _{io}	Input Offset Current (V _{ic} = 0V) T _{min.} ≤ T _{amb} ≤ T _{max.}		5 40	20 40	nA	
I _{ib}	Input Bias Current (V _{ic} = 0V) T _{min.} ≤ T _{amb} ≤ T _{max.}		20	100 200	nA	
A _{vd}	Large Signal Voltage Gain (R _L = 10kΩ, V _o = ±10V) T _{min.} ≤ T _{amb} ≤ T _{max.}	50 25	100		V/mV	
V _{OH}	High Level Output Voltage V _{CC} ⁺ = 5V, V _{CC} ⁻ = 0V, R _L = 10kΩ V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, R _L = 10kΩ V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, R _L = 10kΩ, T _{min.} ≤ T _{amb} ≤ T _{max}		3.5 13.6 13.3	4.2 14.2	V	
V _{OL}	Low Level Output Voltage V _{CC} ⁺ = 5V, V _{CC} ⁻ = 0V, R _L = 10kΩ V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, R _L = 10kΩ V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, R _L = 10kΩ, T _{min.} ≤ T _{amb} ≤ T _{max}			0.1 -14	0.15 -13.6 -13.3	V
I _{sc}	Output Short Circuit Current (V _{id} = ±1V, V _o = 0V) Source Sink	3 15	6 27		mA	
V _{icm}	Input Common Mode Voltage Range T _{min.} ≤ T _{amb} ≤ T _{max}	V _{CC} ⁻ to (V _{CC} ⁺ - 1.8) V _{CC} ⁻ to (V _{CC} ⁺ - 2.2)			V	
CMR	Common-mode Rejection Ratio (V _{ic} = V _{icm} min.)	80	100		dB	
SVR	Supply Voltage Rejection Ratio (V _{CC} = ±5 to ±15V)	80	100		dB	
I _{cc}	Supply Current V _{CC} ⁺ = 5V, V _{CC} ⁻ = 0V, no load V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, no load V _{CC} ⁺ = +15V, V _{CC} ⁻ = -15V, no load, T _{min.} ≤ T _{amb} ≤ T _{max}		200 220	250 250 300	µA	
SR	Slew Rate (V _i = ±10V, R _L = 10kΩ, C _L = 100pF)	1.6	2		V/µs	
GBP	Gain Bandwidth Product R _L = 10kΩ, C _L = 100pF, f = 100kHz	1.4	2.1		MHz	
φm	Phase Margin (R _L = 10kΩ, C _L = 100pF)		45		Degrees	
e _n	Equivalent Input Noise Voltage (f = 1kHz)		29		$\frac{nV}{\sqrt{Hz}}$	
THD	Total Harmonic Distortion		0.05		%	
V _{O1} /V _{O2}	Channel Separation		120		dB	

PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100